

AMENDMENTS TO THE CLAIMS

The following listing of claims will replace all prior versions and listings of claims in the application.

LISTING OF CLAIMS

1. (Currently Amended) ~~A substrate for a liquid crystal device being one of a pair of substrates having a liquid crystal layer interposed therebetween, located on the side opposite to the viewer,~~

~~— wherein the surface on the side of the liquid crystal layer comprises a planar region and a roughened region comprising microscopic peaks and valleys, and~~

~~— the heights of the tops of the peaks in the roughened region are equal to or lower than the level of the plane including the planar region.~~A substrate for a liquid crystal device, comprising:

a planar region and a roughened region, the roughened region comprising microscopic peaks and valleys, tops of the peaks in the roughened region having heights substantially equal to, or less than, a plane of the planar region,

wherein a predetermined mark made of a metal film is formed on the planar region, and a reflecting film made of the same metal film is formed on the roughened region.

2. (Cancelled)

3. (Currently Amended) The substrate for a liquid crystal device according to Claim 21, wherein the predetermined mark is an alignment mark.

4. (Currently Amended) The substrate for a liquid crystal device according to Claim 21, wherein the predetermined mark is a process control mark.
5. (Original) The substrate for a liquid crystal device according to Claim 1, wherein wiring is formed in the planar region.
6. (Original) The substrate for a liquid crystal device according to Claim 1, wherein a sealant is formed in the planar region.
7. (Previously Presented) The substrate for a liquid crystal device according to Claim 1, wherein the maximum height R_y , the arithmetic mean roughness R_a , the ten-point average roughness R_z , and the mean wavelength S_m in the roughened region are in predetermined ranges.
8. (Original) The substrate for a liquid crystal device according to Claim 7, wherein the maximum height R_y is set at 0.2 to 3 μm , the arithmetic mean roughness R_a is set at 0.02 to 0.3 μm , the ten-point average roughness R_z is set at 0.1 to 2.5 μm , and the mean wavelength S_m is set at 4 to 60 μm .
9. (Original) The substrate for a liquid crystal device according to Claim 7, wherein the maximum height R_y is set at 1.5 to 2.0 μm , the arithmetic mean roughness R_a is set at 0.15 to 0.3 μm , the ten-point average roughness R_z is set at 1.3 to 1.8 μm , and the mean wavelength S_m is set at 15 to 25 μm .

10. (Original) The substrate for a liquid crystal device according to Claim 7, wherein the maximum height Ry is set at 0.7 to 1.2 μm , the arithmetic mean roughness Ra is set at 0.1 to 0.2 μm , the ten-point average roughness Rz is set at 0.5 to 1.0 μm , and the mean wavelength Sm is set at 35 to 50 μm .

11. (Original) The substrate for a liquid crystal device according to Claim 7, wherein the maximum height Ry is set at 0.6 to 1.2 μm , the arithmetic mean roughness Ra is set at 0.05 to 0.15 μm , the ten-point average roughness Rz is set at 0.5 to 1.0 μm , and the mean wavelength Sm is set at 15 to 25 μm .

12. (Original) The substrate for a liquid crystal device according to Claim 7, wherein the maximum height Ry is set at 0.4 to 1.0 μm , the arithmetic mean roughness Ra is set at 0.04 to 0.10 μm , the ten-point average roughness Rz is set at 0.3 to 0.8 μm , and the mean wavelength Sm is set at 8 to 15 μm .

13. (Original) The substrate for a liquid crystal device according to Claim 7, wherein the maximum height Ry is set at 0.8 to 1.5 μm , the arithmetic mean roughness Ra is set at 0.05 to 0.15 μm , the ten-point average roughness Rz is set at 0.7 to 1.3 μm , and the mean wavelength Sm is set at 8 to 15 μm .

14. (Previously Presented) The liquid crystal device comprising a liquid crystal layer interposed between a substrate for a liquid crystal device according to Claim 1 and another substrate.

15. (Original) The electronic apparatus comprising a liquid crystal device according to Claim 14.

16-23. (Cancelled)

24. (New) The substrate for a liquid crystal device according to Claim 1, wherein the substrate contains a first composition which is network-shaped and a second composition located in spaces of the network-shaped first composition, and the microscopic peaks and valleys are formed on a surface of the roughened region corresponding to the network-shape of the first composition.

25. (New) A substrate for a liquid crystal device, comprising:
a surface having a planar region and a roughened region, the roughened region comprising microscopic peaks and valleys, tops of the peaks in the roughened region having heights substantially equal to, or less than, a plane of the planar region,
wherein a predetermined mark is formed on the planar region, and a reflecting film is formed on the roughened region.

26. (New) The substrate for a liquid crystal device according to Claim 25, wherein the metal film is composed of an elemental metal, such as aluminum or silver, or an alloy containing aluminum, silver, chromium, or the like, as the principal ingredient.